

Performance of a Kinetic Inductance Phonon-Mediated Detector at the NEXUS Cryogenic Facility

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Microcalorimeters that leverage microwave kinetic inductance detectors to read out phonon signals in the particle-absorbing target, referred to as kinetic inductance phonon-mediated (KIPM) detectors, offer an attractive detector architecture to probe dark matter (DM) down to the fermionic thermal relic mass limit. A prototype KIPM detector featuring a single aluminum resonator patterned onto a 1-gram silicon substrate was operated in the NEXUS low-background facility at Fermilab for characterization and evaluation of this detector architecture’s efficacy for a dark matter search. An energy calibration was performed by exposing the bare substrate to a pulsed source of 470 nm photons, resulting in a baseline resolution on the energy absorbed by the phonon sensor of 2.1 ± 0.2 eV, a factor of two better than the current state-of-the-art, enabled by millisecond-scale quasiparticle lifetimes. However, due to the sub-percent phonon collection efficiency, the resolution on energy deposited in the substrate is limited to $\sigma_E = 318 \pm 28$ eV. We further model the signal pulse shape as a function of device temperature to extract quasiparticle lifetimes, as well as the observed noise spectra, both of which impact the baseline resolution of the sensor.

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I. INTRODUCTION

Null results from searches for particle dark matter (DM) with mass above $1 \text{ GeV}/c^2$ [1] motivate the development of detector technologies that can probe the remainder of the thermal relic parameter space down to the fermionic mass limit of a few keV. The average kinetic energy carried by DM with $1 \text{ MeV}/c^2$ mass is about 500 meV. As such, sensitivity to light DM requires the ability to detect meV-scale quanta. Detectors employing superconducting thin films to sense athermal phonons are a class of sensors that can achieve this requirement. [2].

One detector architecture in this class is the kinetic in-

ductance phonon-mediated (KIPM) detector, which use microwave kinetic inductance detectors (MKIDs) to read out phonon signals in the device substrate [3–8]. Phonons produced by particle interactions in the substrate propagate to the superconducting films on the surface, where they break Cooper pairs into quasiparticles, provided the phonon carries an energy larger than the Cooper pair binding energy, 2Δ . This transient increase in quasiparticle density increases the surface impedance (AC resistance and kinetic inductance) of the resonator, shifting its resonant frequency f_r and quality factor Q to lower values. This shift can be measured in both magnitude and phase by interrogating the resonator with a microwave probe tone at the quiescent resonant frequency and measuring the complex forward scattering parameter S_{21} .

KIPM detectors have a number of attractive features that motivate their use to detect low mass dark matter. The energy carried by a phonon quantum is 2–3 orders of magnitude lower than the electronic bandgap energy of the substrate, which sets the threshold for sensing techniques that rely on ionization production [9]. They are additionally non-dissipative, allowing for the use of QIS techniques to reduce noise (*e.g.*, vacuum squeezing [10], quantum-limited amplification [11, 12]). The sensors themselves are natively frequency-domain mul-

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tipleable, and their high quality factors ($> 10^5$) allow for thousands of resonators to be coupled to a common feedline enabling simple scalability to large arrays [13].

Current state-of-the-art phonon-mediated MKID sensors have demonstrated resolution on energy deposited in the substrate (σ_E) of 26–30 eV [14, 15]. For comparison, phonon-coupled TES detectors have achieved an order of magnitude better resolution [16]. Preliminary results have demonstrated sub-eV resolution with phonon-coupled TES detectors [17]. In order for KIPM detectors to be competitive in the low-mass DM landscape, their resolution must be improved.

In this paper, we report a measurement of the energy resolution of a KIPM detector operated at the North-western EXperimental Underground Site (NEXUS), a low-background cryogenic facility at Fermilab. NEXUS is located 105 meters underground in the MINOS cavern which provides a rock overburden of 225 meters of water equivalent (m.w.e.) [18], reducing the muon flux by a factor of 515 [19] compared to the surface. The heart of the facility is a CryoConcept HEXA-DRY $^3\text{He}/^4\text{He}$ dilution refrigerator [20], which reliably maintains a 10 mK base temperature. The refrigerator is enshrouded by a near-hermetic radiation shield comprising five 4-inch thick walls of Pb bricks and an internal copper-clad Pb slab (also 4 inches thick) below the mixing chamber. The experimental payloads are deployed on a plate thermally coupled to the mixing chamber – but below this internal lead slab. Three sides and the bottom face of the shield are mounted upon a movable cart that can be mated to a vertical lead wall creating a shield closed and shield open configuration. The refrigerator also features an Amuneal A4K magnetic shield integrated into the 4K thermal shield as well as an external magnetic shielding blanket.

II. THE KINETIC INDUCTANCE PHONON-MEDIATED DETECTOR DESIGN

The KIPM detector under test in this work was fabricated at the Jet Propulsion Laboratory and features 11 resonators with resonant frequencies $f_r = 1/2\pi\sqrt{LC}$ in the 3.9–4.4 GHz band deposited on a $2.2 \times 2.2 \text{ cm}^2$, 1 mm thick (~ 1 gram) high-resistivity, double-sided polished silicon substrate. The physical device and its design mask are shown in Fig. 1. The primary phonon-absorbing resonator is formed from a 30-nm-thick Al meandered inductor and an interdigitated capacitor formed from a bilayer of 30 nm each of Al and Nb. The capacitor has a $950 \mu\text{m}$ finger length and $20 \mu\text{m}$ finger width and spacing, while the inductor’s meander width is $80 \mu\text{m}$ with 10 and $20 \mu\text{m}$ spacing, creating a footprint of 0.81 mm^2 . The inductor, which has a volume of $2.4 \times 10^4 \mu\text{m}^3$, serves as the phonon absorber, where incident energy breaks Cooper pairs and modulates the surface impedance of the resonator. The remaining ten resonators are fabricated entirely of Nb, originally intended for a separate

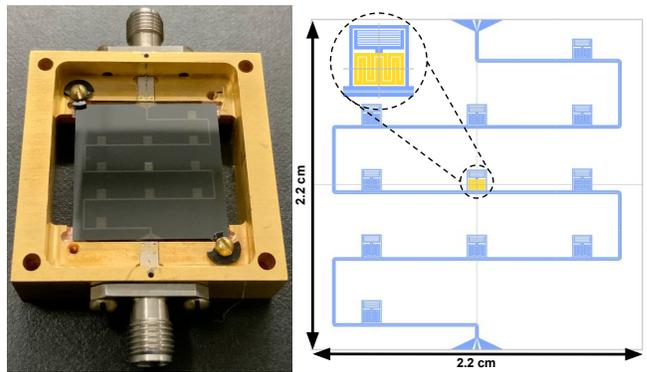


FIG. 1. (Left) The KIPM detector in its housing as deployed at NEXUS for this measurement featuring a central, phonon-absorbing aluminum resonator. (Right) The design mask of the device showing the Nb (blue) and Al (yellow) features, with an inset showing the design of the primary phonon-absorbing resonator.

measurement [7]. The T_c of Nb is a factor of ten larger than that of Al [21], though not large enough to raise its Cooper pair binding energy above the average phonon energy in silicon ($\sim 1 \text{ meV}$) [22]. This introduces an avenue for phonon loss, but phonon recycling [23, 24] from quasiparticle recombination will inject phonons of energy $2\Delta_{\text{Nb}} \approx 2.8 \text{ meV}$ [21, 25] back into the substrate to be absorbed by the Al ($2\Delta_{\text{Al}} \approx 0.36 \text{ meV}$ [21, 25]) with a characteristic timescale given by the quasiparticle lifetime of the higher-gap material. This recycling was expected to maintain the efficiency for phonon collection in Al. All resonators are inductively coupled to a $20\text{-}\mu\text{m}$ -wide, 300-nm -thick, serpentine coplanar waveguide Nb feedline with two $100\mu\text{m}$ -wide ground planes separated by $10 \mu\text{m}$, with a 50Ω characteristic impedance. The resonant frequency of each resonator is tuned by adjusting the length of the inductor.

The silicon chip is housed in a gold-plated copper enclosure with a penetration for an SMA-connectorized optical fiber. Thermalization of the device is accomplished by physical contact with its enclosure on four corners. The device is held in thermal contact with the enclosure by two nylon clip washers on opposite corners fastened with two brass screws. For readout, Al wirebonds connect the CPW feedline to Duroid(TM) launcher boards with a 50-ohm copper CPW feedline and a stainless-steel SMA connector soldered to it.

III. EXPERIMENTAL SETUP

The KIPM detector payload was deployed on the RF payload plate of the NEXUS dilution refrigerator, which is thermally coupled to the mixing chamber plate. Infrared-absorbing inline coaxial filters [26] were connected to the RF input and output of the KIPM device. The RF input line is thermalized at each refrigerator stage with 0 dB attenuators – except at the 4 K

and 10 mK stages, where 20 dB attenuators are used. RF lines with stainless steel conductors are used from 300K to 4K and NbTi from 4K to the mixing chamber. A 10 GHz low-pass filter (RF-Lambda RLPFTBG10) is deployed at the 1K stage. This intentional attenuation and the passive attenuation from warm and cold RF cabling sums to a total of 56.5 dB of attenuation between the RF source and the device input at the Al resonant frequency of 4.242 GHz. This attenuation is used to convert between power at the DAC P_{DAC} and power on the device feedline P_g . The device output is routed through a Low Noise Factory LNF-ISC4_8A single-junction isolator at the 10 mK stage and amplified with a Low Noise Factory LNF-LNC0.3_14A high electron mobility field-effect transistor (HEMT) amplifier mounted at the 4K stage. The output line is similarly thermalized at each refrigerator stage with 0 dB attenuators. Finally, the device output signal is amplified at room temperature using a Mini-Circuits ZX60-83LN-S+ amplifier.

The RF probe tones are generated and later digitized by an Ettus Research x300 Universal Software-defined Radio Platform (USRP), controlled using the GPU_SDR package [27]. The USRP provides a 1 V_{pp} pulse-per-second clock output line which serves as a trigger for an arbitrary waveform generator, which then imprints a desired pulse pattern on the output of a ThorLabs EP470S04 470-nm fiber-coupled LED. The LED photons are routed via optical fiber into the cryostat and to the device. The fiber is thermalized at each temperature stage below 50 K and penetrates the KIPM device enclosure such that the optical photons impinge upon the bare silicon side of the device, ensuring no photons are directly incident on the inductor and all Cooper-pair-breaking energy comes in the form of phonons produced in the substrate. In order to track the optical power delivered with each LED pulse, the current through the LED is monitored by measuring the voltage across a 7.5 Ω shunt resistor.

The resonance features of the device are modeled as notch filters, with the complex transmission as a function of frequency given by (*e.g.*, [28, 29])

$$S_{21}(f, T) = 1 - \frac{Q}{Q_c} \frac{1}{1 + 2jQ \frac{f - f_r(T)}{f_r(T)}}, \quad (1)$$

where $f_r(T)$ is the resonant frequency as a function of temperature, Q_c is the coupling quality factor, and Q is the total quality factor, given by $Q^{-1} = Q_c^{-1} + Q_i^{-1}$ where Q_i is the internal quality factor. This expression represents the idealized S_{21} , where off-resonance transmission has been set to unity. The complex transmission as a function of stimulus frequency $S_{21}(f)$ can be measured and fit to the above equation to extract the characteristics of the resonator. In practice, Eq. (A1) (see Appendix A) is used for fitting to account for non-ideal line shapes and off-resonant transmission. The transmission spectrum of this device in the resonators' band is shown in Fig. 2.

The shift in on-resonance transmission δS_{21} in response to a time-dependent change in quasiparticle density $\delta n_{\text{qp}}(t)$ is given by [30]

$$\delta S_{21}(t) = \alpha \frac{Q_r^2}{Q_c} (\kappa_1 + i\kappa_2) \delta n_{\text{qp}}(t), \quad (2)$$

where t is time, α is the kinetic inductance fraction, and $\kappa_{1(2)}$ carries units of volume and is the real(imaginary) component of the fractional change in complex conductivity per unit change in quasiparticle density. The values of both κ_1 and κ_2 are a function of superconductor temperature T , readout frequency, and superconducting gap energy at zero temperature (Δ), expressions for which are given in [31]. A waveform is acquired by reading out the on-resonance transmission as a function of time. A Cooper-pair breaking event leads to an increased n_{qp} which in turn leads to an a fast reduction (limited by the resonator ringdown time $\tau_r = Q/f_r$) in both resonant frequency and quality factor, usually expressed as fractional shifts $\delta f/f$ and $\delta(1/Q)$. As the broken Cooper pairs recombine, the resonance returns to its quiescent point. The entire process appears as a pulse in the S21 timestream. We adopt values for α and Δ from measurements of an identical device [7]. See Appendix A for a discussion on measuring the zero-temperature characteristics of this device.

IV. KIPM DETECTOR ENERGY RESOLUTION

The energy resolution of the KIPM detector can be determined via exposure of the device to a pulsed source of optical photons. By varying the optical power delivered in a single pulse, one can exploit the broadening of the pulse amplitude distribution due to photon shot noise to infer the total energy deposited in the substrate [32]. If an interaction in the substrate deposits an energy E into the phonon channel, the resonator will absorb an energy $E_{\text{abs}} = \eta_{\text{ph}} E$ where $\eta_{\text{ph}} < 1$ is the efficiency for the resonator to collect energy from the substrate. This efficiency contains contributions from phonon downconversion to energies below the aluminum gap, phonon loss at interfaces (*e.g.*, mounting hardware) and to other superconducting films, and the efficiency for phonon transmission between the superconductor and the substrate. This factor can be used to relate the device energy resolution σ_E (resolution on energy deposited in the substrate) and resolution on energy absorbed by the superconductor σ_E^{abs} (the intrinsic energy resolution of the resonator):

$$\sigma_E = \frac{\sqrt{N_r}}{\eta_{\text{ph}}} \sigma_E^{\text{abs}}. \quad (3)$$

Here, the factor $\sqrt{N_r}$ arises from using N_r resonators to measure an energy signal and adding their resolutions in quadrature. For the device under test we set $N_r = 1$ since we only use the Al resonator to measure energy depositions, and fold any phonon loss due to the Nb resonators into η_{ph} .

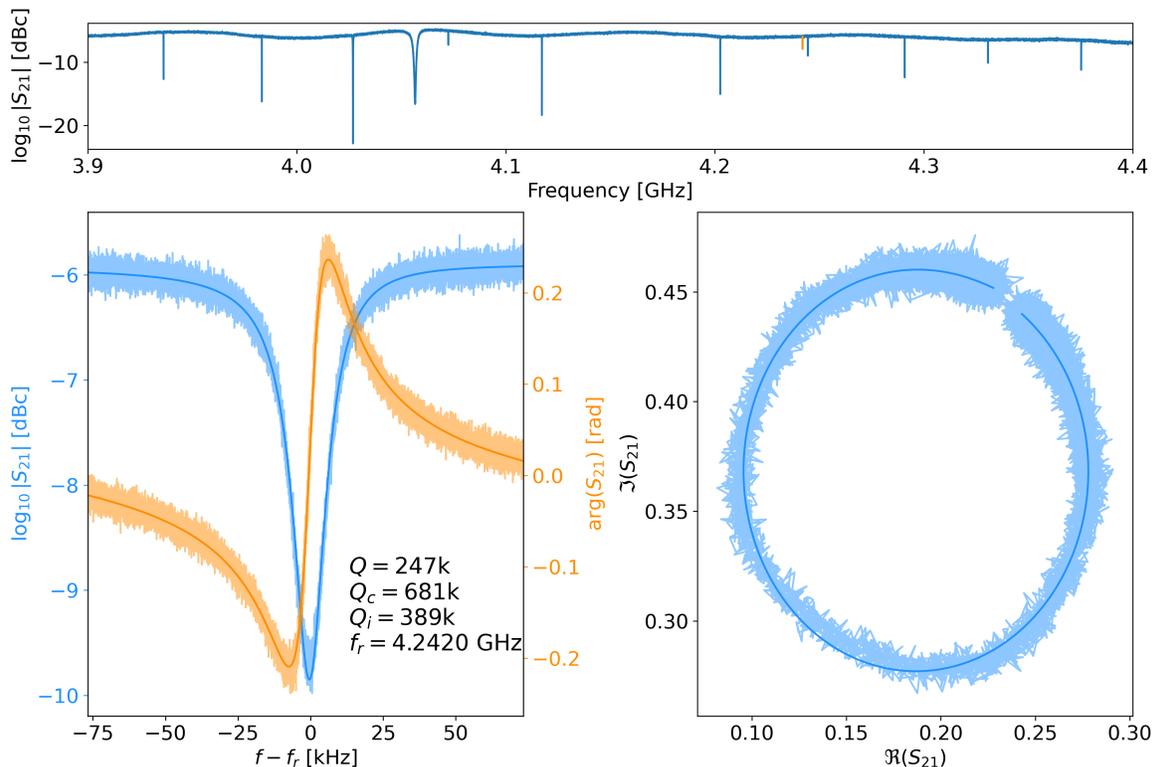


FIG. 2. (Top) The logarithmic magnitude of the forward scattering parameter S_{21} (transmission) of the KIPM device in the resonators' frequency band. The Al resonator is shown in orange. (Bottom left) In blue is the logarithmic magnitude of the Al resonance feature, while in orange is the phase response vs frequency relative to the resonant frequency. The resonance's parameters are listed. (Bottom right) The phonon-sensitive resonance in complex S_{21} space. These data are acquired with a power on the feedline of $P_g = -106.5$ dBm at a device temperature of 10 mK. Fits to the resonance lineshape Eq. (1) are shown as solid lines.

The baseline (zero-energy) resolution of a resonator is set by the level of on-resonance noise, contributed by sources including the thermal noise of the first-stage amplifier, noise from electrically active two-level systems (TLS) present in oxide layers of the device [7, 33, 34], and from Poissonian fluctuations in the density of quasi-particles in the superconductor due to thermal excitation (generation-recombination noise [35, 36]). The on-resonance noise can be characterized by its power spectral density (PSD). The on-resonance noise PSDs for the two readout quadratures at base temperature, for a range of readout powers, and a brief discussion of noise sources present can be found in Appendix B.

The baseline resolution can be determined with an optimal filter [37] by comparing a signal template in the frequency domain with complex component \tilde{s}_n in the n^{th} frequency bin to the noise PSD, $J(f_n)$, in the same frequency bin. In this case, the baseline resolution σ_0 is

given by the square-root of

$$\sigma_0^2 = \left[D \sum_{n=-\frac{N}{2}}^{\frac{N}{2}-1} \frac{|\tilde{s}_n|^2}{J(f_n)} \right]^{-1}, \quad (4)$$

where D is the total duration of the signal timestream s_n and N is the total number of frequency bins. The resolution calculated in this fashion, for a unit-normalized signal template, inherits units from J (e.g., if J has units of $(\delta f/f)^2/\text{Hz}$, then σ_0 carries units of $\delta f/f$).

V. OPTICAL PHOTON CALIBRATION

A. Data collection

The KIPM detector was exposed to a pulsed source of 470 nm (2.6 eV) photons with variable optical power, up

to 7 mW^1 . For each optical power, the LED bias V_{LED} is modulated by a pulse generator enabling control of the photon pulse width and arrival time relative to the start of data acquisition. The data acquisition for the energy calibration proceeds as follows. With the LED disabled, 30-second timestreams of noise are acquired for three probe tones: one at f_r and the others taken at a $\pm 10 \text{ MHz}$ offset from f_r . These off-resonant tones, taken at the same RF stimulus power, are used for removal of correlated electronics noise present in the on-resonance timestream [7]. The pulse generator output is then enabled, with an output pulse voltage of $V_{\text{LED}} = 5.0 \text{ V}$, corresponding to the largest optical power used. For the calibrations presented in this work, we use a pulse width of $2 \mu\text{s}$ delivered at 5 Hz . A 5-ms delay is applied to the pulse generator such that the first optical pulse arrives 5 ms after the start of the timestream acquisition. With the LED pulsing, 200-second timestreams are acquired at the same three tones. The on-resonance timestream therefore contains 1,000 windows in which LED pulses may be found. The pulse voltage (LED bias) is lowered to the next setpoint (0.5 V steps) and data are acquired in the same fashion. After every three LED timestreams are acquired, the pulse generator is disabled and a noise timestream is acquired, as described above. The lowest V_{LED} is chosen such that the LED does not receive a sufficient forward voltage to emit light. This data set serves to test for electronic pickup from the LED pulsing setup. The turnoff voltage in this setup is $V_{\text{LED}} = 2.0 \text{ V}$.

This calibration was performed twice, once in February 2023 and once in July 2023, with the same device under slightly different environmental conditions. The February calibration was performed with an RF power at the output of the USRP of $P_{\text{DAC}} = -16 \text{ dBm}$ at a device temperature of 15 mK , while the calibration in July was acquired with $P_{\text{DAC}} = -15 \text{ dBm}$ and a device temperature of 10 mK .

B. Energy resolution analysis

Once the data have been acquired, they are processed offline. The first 10% of pulse windows (a total of 20 seconds) at the start of an acquisition are discarded to avoid any transient behavior of the USRP as the continuous-wave RF stimulus begins and the RF circuitry reestablishes equilibrium. Then, each of the 900 remaining 200-ms windows is evaluated for its noise properties and pulse location in time. In the pre-trigger region, defined to be the first 4.75 ms of the pulse window, the mean and RMS of the noise are used to reject windows in which there is increased noise (RMS) or a baseline jump (mean). For each LED setting, the distribution of these parameters

for all 900 windows is investigated and its 5th- and 90th-percentile values are used to define the cut limits. These limits were adjusted manually for acquisitions where the distributions had non-Gaussian features. Events in which a point exists in the pre-trigger region with an amplitude larger than $3.5\times$ the pre-trigger RMS are removed from analysis. Similarly, events in which a point exists in the post-pulse region, defined to be the remainder of the window beyond 7.5 ms, with an amplitude larger than $4\times$ the post-pulse RMS are removed from analysis. A further quality cut is applied to ensure that the pulse occurred at the time expected from the LED pulse. Any window in which the maximum occurs more than 4 samples away from the trigger time is removed from analysis if there exists a point anywhere in the window with an amplitude greater than $5\times$ the pre-trigger RMS. The conditional on this cut is intended to retain windows in which there are no pulses (*i.e.*, if the LED voltage is too low to produce a signal over noise). A graphical depiction of these various time regions is shown in Fig. 3. These quality cuts are evaluated on the κ_1 readout quadrature, and retain $\sim 60\%$ of the pulse windows.

Pulse timestreams are cleaned of correlated electronic noise using measurements of the correlation in noise timestreams. For every LED voltage, each pulse window surviving the quality cuts is then split in two 100-ms halves to define a signal region (first half) and signal-free region (second half). The PSD of the cleaned signal-free region, $J(f)$, is calculated for each window, then averaged over the windows for each LED setting. These average pulse-free PSDs, shown in Fig. 4, are compared to the noise-only PSD to confirm no signal has leaked into the signal-free region and to each other to confirm compatibility of the data. The observed noise at this readout power is far from white and is dominated by TLS noise (see Appendix B), which is the primary limiter of our sensors' energy resolution. Investigations into resonator design optimization for mitigating the presence of TLS sites and their impact on the overall noise are underway.

The signal region of every pulse window surviving cuts is baseline-subtracted and averaged to determine the pulse shape, shown in Fig. 5. The average pulse from the largest LED voltage defines the signal template. With the Fourier-transform of this template $\tilde{s}(f)$ and the average noise PSD, the fractional baseline resolution σ_0 is found using Eq. (4) for both the phase and magnitude readout quadratures. These are then scaled by the maximum amplitude of the un-normalized time-domain signal templates in $\delta f/f$ and $\delta(1/Q)$ to obtain the resolution in changes of the resonator's characteristics. The resolutions are converted into resolution on changes in quasi-particle density, as measured by the phase (frequency, κ_2) and magnitude (dissipation, κ_1) readout quadratures, by way of Eq. (2). These results are summarized for both calibration runs in Table I. While the resolution calculated in this fashion carries some uncertainty due to the relationship between a particular realization of noise and its PSD (see Appendix B of [37]), we report no baseline

¹ At the input of the room-temperature optical feed-through of the dilution refrigerator.

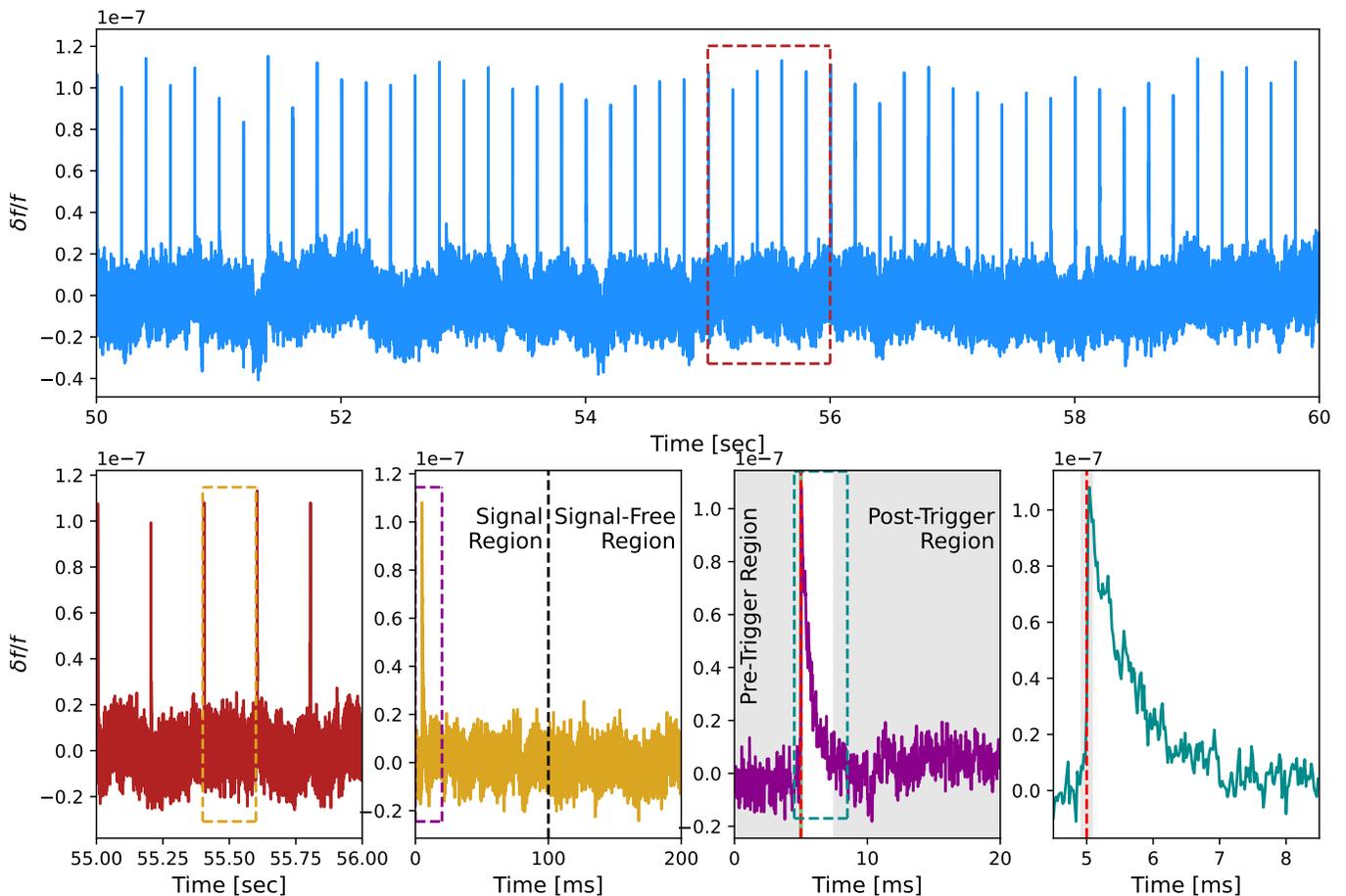


FIG. 3. Example timestream of LED pulses: (top) 10 second window; (bottom left) 1 second window; (bottom middle left) a single pulse window; (bottom middle right) a zoom-in on the signal window near the pulse showing the pre-trigger and post-pulse regions; (bottom right) a closer zoom-in on the signal window to demonstrate the window in which the pulse maximum must arrive. These time regions are used to evaluate cuts as well as define the signal and noise region of each pulse window.

resolution uncertainty for two reasons: (1) this uncertainty amounts to $< 1\%$ and thus the dominant uncertainty on resolution in quasiparticle density (from which the resolution on energy absorbed by the sensor σ_E^{abs} is calculated) arises from the calculation of $\kappa_{1,2}(T)$ due to differences between the physical device temperature and the effective temperature of the Cooper pairs, amounting to a relative uncertainty of roughly 9% as discussed in Appendix D; and (2) the values in Table I are not used to determine the device energy resolutions and serve only as a point of reference.

Resolution in quasiparticle density fluctuations, as measured in the κ_1 or κ_2 direction $\sigma_0^{\kappa_{1,2}}$, can be translated into a resolution on energy absorbed by the sensor: $\sigma_E^{\text{abs}} = \Delta \sigma_0^{\kappa_i} V$, where Δ is the superconducting gap energy and V is the volume of the superconductor in which the Cooper pairs are broken. However, determination of the resolution on energy deposited in the substrate requires knowledge of η_{ph} , provided by the LED calibration procedure described above.

For a single pulse window, the best estimator for the

TABLE I. The baseline resolution estimates, Eq. (4), from dedicated noise acquisitions taken during each of the calibration runs. The average pulse with largest amplitude is used as the signal template. In the phase and magnitude readout quadratures, σ_0 is reported as a fraction of the amplitude of the average pulse. The resolutions are also reported in terms of fractional shifts in resonator characteristics ($\sigma_0^{df/f}$, $\sigma_0^{1/Q}$) and as fluctuations in quasiparticle density ($\sigma_0^{\kappa_2}$, $\sigma_0^{\kappa_1}$) in μm^{-3} .

Date	Feb 15, 2023	Jul 13, 2023
σ_0 (phase)	7.8×10^{-3}	9.8×10^{-3}
σ_0 (mag.)	3.2×10^{-2}	4.0×10^{-2}
$\sigma_0^{df/f}$	3.6×10^{-9}	5.2×10^{-9}
$\sigma_0^{1/Q}$	7.4×10^{-9}	1.1×10^{-8}
$\sigma_0^{\kappa_2} [\mu\text{m}^{-3}]$	0.48	0.70
$\sigma_0^{\kappa_1} [\mu\text{m}^{-3}]$	0.86	1.24

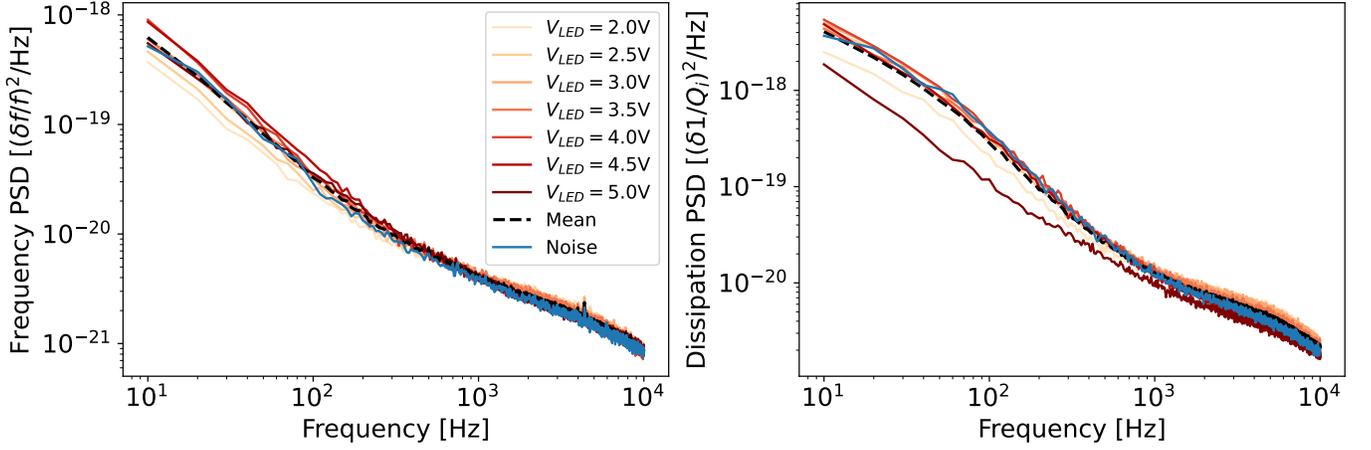


FIG. 4. The average PSDs in the frequency (left) and dissipation (right) directions for the pulse-free region for each LED voltage. The mean of these PSDs is shown in the black dashed line. The PSD from a dedicated noise acquisition before the LED data acquisition is shown in blue. Only the frequency-direction readout is used for the energy resolution analysis. For a decomposition of these noise spectra and a discussion of noise sources, see Appendix B.

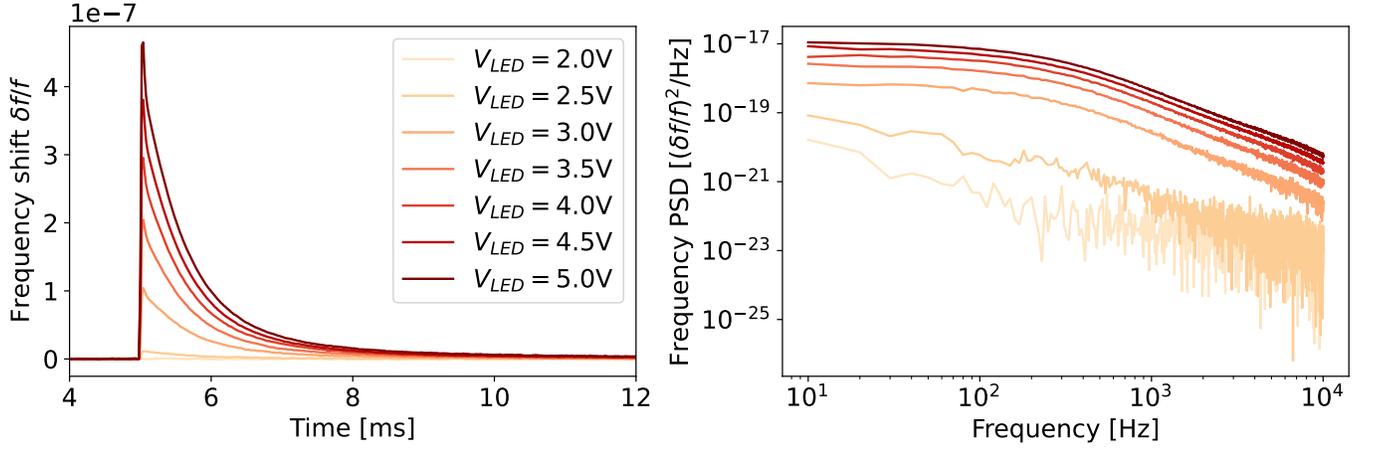


FIG. 5. The average pulse shape in the time (left) and frequency (right) domains for each LED voltage. Each pulse window begins at 0 ms and extends to 100 ms.

pulse amplitude A is

$$\hat{A} = \frac{\sum_{n=-\frac{N}{2}}^{\frac{N}{2}-1} \frac{\tilde{s}_n^* v_n}{J(f_n)}}{\sum_{n=-\frac{N}{2}}^{\frac{N}{2}-1} \frac{|\tilde{s}_n|^2}{J(f_n)}}, \quad (5)$$

where n is an index of frequency bins and v_n is the Fourier transform of the signal-region timestream for each pulse window [37, 38]. In our case, we choose the frequency-domain signal template \tilde{s}_n to be the average pulse from the largest LED bias voltage, the complex conjugate of which is \tilde{s}_n^* . The estimator \hat{A} is calculated for the signal-region of each pulse window, and their distribution for each LED voltage is shown in Fig. 6.

The distribution of pulse amplitudes for a given voltage in our readout units, assuming a detector response linear with deposited energy, has a mean $\mu = R\bar{E}_{\text{abs}} = R\eta_{\text{ph}}\bar{E} = R\eta_{\text{ph}}h\nu\bar{N}_\gamma$ where R is the responsivity in

readout units per unit energy absorbed by the sensor, $h\nu = 2.6$ eV is the energy of a single photon, and $\bar{E} (\bar{N}_\gamma)$ is the average energy (number of photons) deposited in a single flash. The width σ of each distribution is assumed to have contributions from two independent fluctuations: the intrinsic device noise σ_0 and the Poissonian fluctuation in the number of photons delivered per LED flash σ_{LED} :

$$\sigma^2 = \sigma_0^2 + \sigma_{\text{LED}}^2, \quad (6)$$

where these various σ s all have the same units as the readout timestream. As dictated by Poisson statistics, the variance in number of photons delivered is $\sigma_{\bar{N}_\gamma}^2 = \bar{N}_\gamma$, which implies (see Appendix C for derivation) the variance in pulse amplitudes is

$$\sigma_{\text{LED}}^2 = (R\eta_{\text{ph}}h\nu)^2 \bar{N}_\gamma. \quad (7)$$

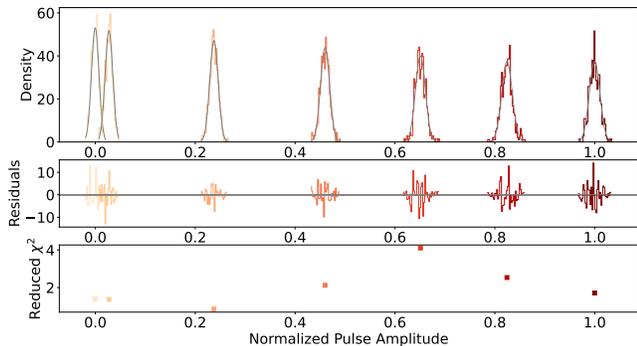


FIG. 6. Results of the LED calibration: distributions of pulse amplitude estimators for each LED voltage, overlaid with Gaussian fits. The colors represent the LED bias voltage, as in Fig. 5. Fit residuals and reduced χ^2 values are shown in the panels below. The amplitude values have been normalized to the amplitude of the average pulse in fractional frequency shift for the largest LED voltage.

Using this expression, where \bar{N}_γ has been substituted using the expression for the distribution mean μ , Eq. (6) becomes

$$\sigma^2 = \sigma_0^2 + r \cdot \mu, \quad (8)$$

where $r = R\eta_{\text{ph}}h\nu$ is the responsivity per photon (*i.e.*, carries the same units as readout). The μ and σ are found for the pulse amplitude distribution at each LED bias setpoint from unbinned Gaussian fits and are fit to the above equation to determine r and σ_0 , the results of which are shown in Table II. These carry units of fraction of largest average pulse amplitude in $\delta f/f$. The uncertainty on the width of each pulse amplitude distribution is the quadrature sum of the statistical errors returned by the fitting routine and our systematic uncertainty. The latter is estimated from the variance in pulse amplitude estimator distribution widths from the signal-free region of each pulse window. This uncertainty arises from drifts in the noise PSD. Note that the baseline resolution inferred from this method and the baseline resolution measured from the signal template and noise timestreams alone are consistent to 1.3σ .

The resolution on energy deposited in the substrate is given by the ratio of the baseline resolution in readout units to the responsivity per unit energy: $\sigma_E = \sigma_0/(r/h\nu)$. For the February calibration, we determine $\sigma_E = 318 \pm 28$ eV. Following the same prescription for determining the resolution on quasiparticle fluctuations as before, we find $\sigma_{\text{qp}}^{\kappa_2} = 0.47 \pm 0.04 \mu\text{m}^{-3}$, from which we infer the resolution on energy absorbed by the superconductor to be $\sigma_E^{\text{abs}} = \sigma_{\text{qp}}^{\kappa_2} V \Delta = 2.1 \text{ eV} \pm 0.2$, using $V = 2.4 \times 10^4 \mu\text{m}^3$ for the Al inductor. The phonon collection efficiency η_{ph} is determined from Eq. (3): $\eta_{\text{ph}} = \sigma_E^{\text{abs}}/\sigma_E = (0.66 \pm 0.08)\%$ for $N_r = 1$ resonators read out. These values, along with the device responsivity R in fractional frequency shift per unit energy deposited

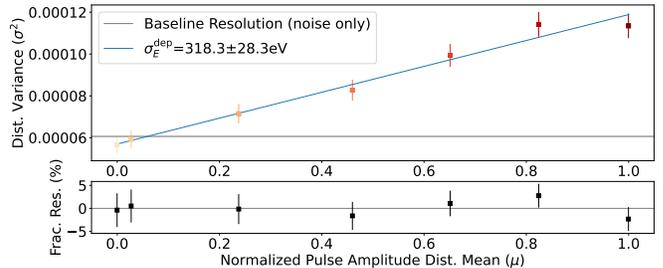


FIG. 7. Results of the LED calibration: variance (σ^2) vs. mean (μ) of the Gaussian fits to distribution of pulse amplitude estimators for each LED voltage, demonstrating their linear relation. The marker colors indicate LED voltage, as in Fig. 5. The fit to the two-component resolution model is shown in blue, while the baseline resolution determined from noise traces and a signal template is indicated by the grey line. Fractional residuals of the data to the fit are shown in the lower panel. The values have been normalized to the amplitude of the average pulse for the largest LED voltage. The error bars represent the total of statistical and systematic errors, the latter estimated from the variance in distribution widths from noise-only acquisitions.

in the substrate, are presented for the two calibration runs in Table II. The deposited energy scale can be reconstructed using R and η_{ph} . With this reconstructed energy scale, we find the average energy deposited in the substrate with each pulse at the largest V_{LED} to be 42 keV, corresponding to a mean of 1.6×10^4 photons absorbed by the substrate per pulse.

TABLE II. Results of the energy resolution measurement for both calibration runs. The fit parameters r and σ_0 are given as a fraction of the largest average pulse amplitude in $\delta f/f$. The responsivity per unit energy absorbed by the sensor $R = (r/h\nu)/\eta_{\text{ph}}$ is given in eV^{-1} , and represents the change in $\delta f/f$ pulse amplitude per eV of phonon energy absorbed by the sensor. The responsivity per unit energy deposited in the substrate is the product of R and the phonon collection efficiency. The sensor and device energy resolutions and phonon collection efficiency from each calibration are also presented. The rightmost column indicates the difference between the two calibration results as a fraction of the combined uncertainty.

	Feb 15, 2023	Jul 13, 2023	Compatibility
r	$(6.2 \pm 0.5) \times 10^{-5}$	$(7.3 \pm 0.6) \times 10^{-5}$	1.4σ
σ_0	$(7.5 \pm 0.2) \times 10^{-3}$	$(8.8 \pm 0.1) \times 10^{-3}$	2.4σ
R [eV^{-1}]	$(3.7 \pm 0.4) \times 10^{-3}$	$(3.2 \pm 0.5) \times 10^{-3}$	0.8σ
σ_E^{abs} [eV]	2.1 ± 0.2	2.8 ± 0.3	1.9σ
σ_E [eV]	318 ± 28	315 ± 28	0.08σ
η_{ph} [%]	0.66 ± 0.1	0.89 ± 0.11	1.7σ

VI. QUASIPARTICLE LIFETIME MEASUREMENT

The observed pulses have ms-scale lifetimes, as shown in Fig. 5. The importance of pulse lifetime can be inferred from the construction of the optimal filter estimate for energy resolution, Eq. (4): as the pulse lifetime increases, the signal template roll-off moves to lower frequency, shifting the signal weights in the sum for the resolution Eq. (4) from higher frequencies to lower frequencies. This effect holds so long as the noise dependence with frequency is shallower than f^{-1} , though gains in resolution are highest when the noise is white. If one considers the case for white amplifier noise and a signal template given by a single falling exponential with time constant τ , one determines the energy resolution scales as $\tau^{-1/2}$, as shown in [39]. If instead, the noise is TLS-like ($f^{-1/2}$) rather than white, the energy resolution scales as $\tau^{-1/4}$. In both cases, longer pulse lifetimes lead to improved resolution, though TLS noise limits this gain. It is thus instructive for device design to understand the signal time constants at play, as well as the sources of noise, to optimize energy resolution.

One contribution to the pulse lifetime is the quasiparticle lifetime τ_{qp} , which depends on the device temperature. The quasiparticle lifetime can be determined by the roll-off in the noise PSD in the case the noise is dominated by generation-recombination noise [36]. This is not the case for the system under test in this work, but τ_{qp} can be estimated from pulse data by fitting pulses taken at varying temperature to a pulse shape model. However, this approach tends to overestimate quasiparticle lifetimes at large ($\gtrsim 250$ mK) temperatures [35]. Additionally, saturation of measured quasiparticle lifetimes compared to theory are seen for $T \lesssim 170$ mK, in both pulse and noise PSD measurements.

A. Data collection & processing

The temperature of the mixing chamber (MC) is maintained with a PID-controlled heater. The MC temperature is swept from the base temperature 25 mK to a maximum of 325 mK, in steps of 25 mK. At each temperature, noise-only and LED pulse timestreams are acquired, each with simultaneous acquisition of calibration tones at $f_r \pm 10$ MHz for cleaning of correlated noise. The RF stimulus power used for this study was $P_{DAC} = -30$ dBm. We used a lower power than the energy resolution measurement, where it was desirable to minimize the baseline resolution contribution. Once the temperature PID stabilized, the LED bias is set to $V_{LED} = 4.0$ V, pulse output is enabled, and timestreams are acquired. These data were acquired directly following the February energy calibration data acquisition. Once these data were collected, the same quality cuts, cleaning process, and average pulse identification were performed as in the energy calibration. The average pulses were then fit to

a pulse shape model, defined below, to extract physical parameters of interest, including τ_{qp} .

Due to slow thermalization of the RF payloads to the MC, where the temperature control thermometer and heater are situated, the device temperature is not the same as the MC temperature T_{MC} . To account for this, a map from MC temperature to device temperature was developed using data from an auxiliary thermometer installed on the RF payload plate during later runs of the NEXUS dilution refrigerator. The discrepancy in temperature is worse at higher MC temperatures, leading to an increased uncertainty in device temperature. The uncertainties on temperature presented in this section represent the standard deviation of the temperature as read by the auxiliary thermometer for a given MC temperature setpoint.

B. Empirical pulse shape model

The average pulse shapes shown in Fig. 5 show structure not described by a single exponential fall time, but rather a shape with two fall time constants: one prompt (τ_p) and one delayed (τ_d). As in [40], we choose to model these pulses as the sum of independent prompt and delayed components

$$s_p(t) = (1 - e^{-(t-t_0)/\kappa_p})e^{-(t-t_0)/\tau_p} \quad (9)$$

$$s_d(t) = (1 - e^{-(t-t_0)/\kappa_d})e^{-(t-t_0)/\tau_d} \quad , \quad (10)$$

which produce an average pulse with shape

$$s(t) = A(s_p(t) + w_d s_d(t)) \quad . \quad (11)$$

This model has 6 free parameters: the two fall time constants, the two rise time constants κ_p and κ_d , an overall amplitude A , and the weight w_d of the delayed component relative to the prompt component. The trigger time t_0 is known and fixed to 5 ms.

Examples of average pulses fit to this model for $T_{MC} = 325$ mK and $T_{MC} = 25$ mK are shown in Fig. 8 and demonstrate good agreement with the data, which is observed across all temperatures. The time constants extracted from the above model are shown as a function of estimated device temperature in Fig. 9. Both the prompt and delayed fall-time constants decrease monotonically as the temperature increases. The peak δn_{qp} (maximal pulse amplitude) was observed to change with temperature, as seen in Fig. 8. While we account for the temperature dependence of κ_2 , there is possible discrepancy between the quasiparticle temperature and the measured device temperature. Any variation in κ_2 due to this is not large enough to explain this, and any difference in Q_i due to temperature is incorporated already in the conversion to the quasiparticle basis. The process of constructing a quantitative model is ongoing.

The data acquired at 110 mK, while fit well by the two-component model, returned with large uncertainty on the

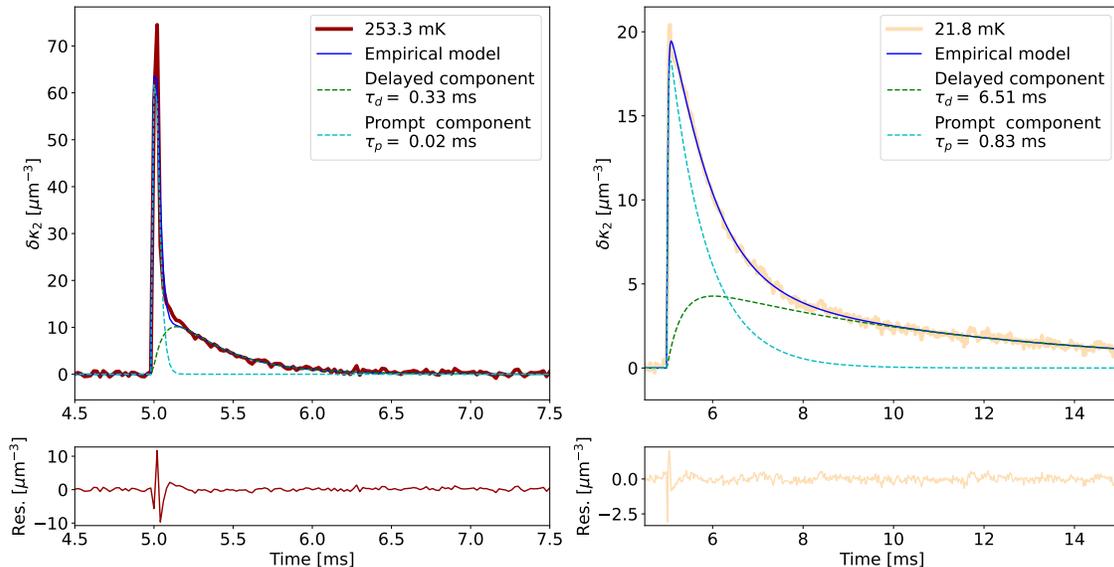


FIG. 8. The average quasiparticle density response in the κ_2 direction for the same LED voltage (optical power) at $T = 253$ mK (left) and $T_{MC} = 22$ mK (right). At both temperatures, a fit to the two-component empirical model is shown in blue, with the prompt and delayed components in dashed cyan and dashed green, respectively. The data are fitted out to 15.0 ms. The lower panels show the residuals of the fit. This model fits pulse data well across all temperatures investigated.

prompt component fall time, due to the degeneracy of delayed amplitude and prompt lifetime (i.e. increasing w_d can compensate for shorter τ_p). For this reason, we also fit this pulse to the single-component model in Eq. (9). For this temperature only, the fit to this model accurately captures the shape, except at the latest times before returning to baseline, where the fit underestimates the pulse. This allows us to identify the single fall time constant as the prompt component, which is indicated by the purple triangle in Fig. 9. The fall time extracted from this falls upon the same line as the low-temperature prompt fall time constants, and was not included in the fit to determine the blue line in Fig. 9.

A priori (and in a manner consistent with [4]), we had ascribed respectively, τ_p and τ_d to the quasiparticle and phonon lifetimes. We depart from the interpretation in [4] and present the following novel interpretation for the two lifetime model: (1) there is one time constant that shows a relatively weak dependence on temperature, as would be expected of an athermal phonon population; and (2) there is a second time constant that shows a much stronger dependence on temperature, precipitously rising at low temperature. The first time constant is drawn suggestively as following the blue line in Fig. 9. The trend of the second time constant is drawn suggestively as the green line. In such a model, the lifetime that varies slowly with temperature is the phonon lifetime while the one that varies quickly is the quasiparticle lifetime, τ_{qp} . The phonon lifetime represents the characteristic time

for the phonon population in the substrate above the Al pair-breaking energy to decay, presumably due to anharmonic and surface-promoted downconversion in the substrate, absorption in the resonator, loss of energy absorbed in Nb films to sub- $2\Delta_{Al}$ phonons, and absorption in the mounting hardware. The quasiparticle lifetime becomes short at high temperature because of the elevated thermal quasiparticle density: $\tau_{qp} \sim (2\Gamma n_{qp})^{-1}$ where Γ is the quasiparticle recombination constant and n_{qp} increases with temperature. It begins to rise precipitously at low temperature due to the exponential suppression of thermal quasiparticles by the superconducting gap. It saturates at low temperature due to various mechanisms that may stop this exponential suppression: readout power generation of quasiparticles, generation of quasiparticles by ambient ionizing radiation, or some other mechanism that maintains a non-thermal quasiparticle density. Under this hypothesis, the τ_{qp} measurements, while discrepant with theoretical calculation from [41], show qualitative agreement in magnitude and shape with [35]. Under this assumption, quasiparticle lifetimes extend up to the several-millisecond scale at the lowest temperatures (6.5 ms), also consistent with [35, 36], corresponding to a quiescent thermal quasiparticle population of $n_{qp,0} = 18.5 \mu\text{m}^{-3}$ [41], the lowest that has ever been measured, to the knowledge of the authors.

This pulse shape model, while adequately describing the observed data, is not without shortcomings. Pri-

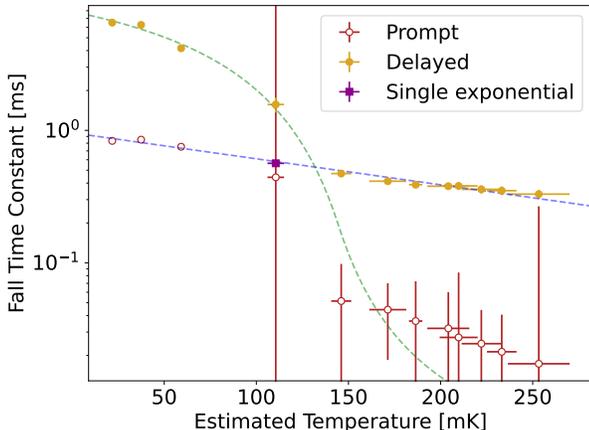


FIG. 9. The prompt (open red circles) and delayed (filled yellow circles) fall-time constants for the empirical model as a function of device temperature. Time constant uncertainties are statistical and are returned by the fitting routine. Temperature uncertainties are derived from our temperature map. Analytic curves (blue and green dashed) have been fit to the data under the hypothesis the role of τ_{qp} changes from τ_d to τ_p around 125 mK. The green curve, which tracks the quasiparticle lifetime, is qualitatively consistent with the shape of the dependence reported in [35]. The blue curve tracks the effective phonon lifetime. The 110 mK pulse was also fit to a single component model, Eq. (9), whose fall time constant is indicated by the purple square. Note that this point was not used in the determination of the blue curve, but nonetheless falls right on top.

marily, as the sensor only measures the quasiparticle response in the superconductor, the phonon and quasiparticle components should not be separable. Rather, one should expect the pulse shape to be a convolution of the phonon time dependence and the quasiparticle lifetime. Evaluation of a class of such models is left for a future investigation.

VII. DISCUSSION

The device under test demonstrated a best baseline resolution on energy absorbed by the sensor of $\sigma_E^{\text{abs}} = 2.1 \pm 0.2$ eV, and a resolution on energy deposited in the substrate of $\sigma_E = 318 \pm 28$ eV. From these values, we measure the phonon collection efficiency η_{ph} to be at the sub-percent level. While the overall energy resolution is poor, the measured resolution on energy absorbed by the sensor (σ_E^{abs}) is a factor 1.5–3 better than demonstrated previously in the literature for KIPM detectors [5, 15]. The model used to evaluate the energy resolution provides a clear two-pronged approach toward achieving the sub-eV resolutions required to probe MeV-scale DM models: (1) improving σ_0 by reducing the noise temperature of the first-stage amplifier and mitigating

the presence of TLS sites to lower the intrinsic device noise; and (2) improving the phonon collection efficiency η_{ph} . The latter can be accomplished by reducing high-gap metal on the substrate and improving device mounting to reduce phonon loss. Collection efficiencies as high as 30% have been demonstrated with other superconducting sensors [16]. Given the comparable collection efficiency achieved by other KIPM detectors, this should be achievable with our device architecture, and alone would improve our σ_E to roughly 10 eV.

All parameters measured in the energy calibration are statistically compatible to 2σ , with the exceptions of the baseline resolution, which is marginally worse for the later calibration. However, despite this difference, the resolution on energy deposited in the substrate is in good agreement. While σ_E^{abs} depends on specifics of the superconductor’s properties that can change with time, the measured σ_E is only dependent on the increased broadening in pulse amplitude distributions from the photon shot noise. This consistency confirms we have correctly reconstructed the absolute energy scale in both calibrations, as the device is detecting the same number of photons for the same optical calibration platform settings. Discrepancies in σ_E would indicate either a problem in our analysis or an instability in our optical calibration system. The reason for the change in device performance between the two LED calibrations is not known with certainty, but we note that the device underwent six thermal cycles and exposure to atmosphere between calibrations, potentially leading to changes in film structure or oxide growth.

The resolution achieved by our sensor (σ_E^{abs}) is primarily due to the ms-scale pulse lifetimes, which enable resolution of photon shot noise despite the presence of TLS noise. For comparison, in a nominally identical device operated in a dilution refrigerator at Caltech pulse lifetimes were limited to a few hundred μs between 50 and 100 mK. Potential reasons for the longer lifetimes in NEXUS are the lower base temperature, lower ionizing particle background, and better blackbody radiation environment. The latter will be tested by improving the blackbody radiation shield in the Caltech facility in the future.

We have introduced a signal model comprising two fall time constants: one prompt and one delayed. This model allows us to extract τ_{qp} from our pulse data. Quasiparticle lifetimes as high as 6.5 ms were observed.

We are developing a simulation using the G4CMP [42] package to understand the phonon collection efficiency by modeling phonon downconversion in high-gap materials, phonon loss at interfaces, and the dependence of phonon collection on fill fraction (ratio of phonon-absorbing inductor surface area to substrate surface area). The results of this simulation will both inform design choices for new KIPM detector architecture and allow us to investigate signal pulse models in-depth, including phonon recycling effects. Furthermore, the same simulation can be used to investigate the pulse model introduced in sec-

tion VI, as we can directly tune τ_{qp} and the phonon lifetime and compare them to the results of fitting to this model. A new batch of KIPM detectors was recently fabricated to understand the dependence of η_{ph} on the fill fraction.

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DJT commissioned the KIPMD data acquisition system, collected the data, performed the analysis, and drafted the manuscript. OW fabricated the device under test in this work, using funds provided by SG. OW and KR motivated the physical interpretation of the two-component signal model, and in conjunction with SG, contributed expertise in phonon and quasiparticle dynamics and MKID operation. LH led the management and supervision of this project. NK conceived of this project on the original LDRD award and participated in the RF upgrade of NEXUS. SL and DBo participated in the RF upgrade of NEXUS. DBa led the QSC project which supported this work following conclusion of the initial project funding (LDRD). EF-F led the management of the NEXUS facility. MH, CJ, and PL contributed to the management and operation of the NEXUS facility. RC, KK, and RR contributed to the operation of the NEXUS facility. VN and BS contributed to the management, upgrade and operation of the NEXUS facility, and led the work to characterize the radiogenic background present at this facility. CB contributed to the design and simulation of the magnetic shield at NEXUS.

Appendix A: Fits to Mattis-Bardeen Theory

The zero-temperature parameters of the resonator, $f_r(T=0)$, $Q_i(T=0)$, α , and Δ , can be extracted by measuring the resonance shape, in frequency-space, as a function of temperature. For a given temperature, the

resonance line shape is fit to a model given [31] by

$$S_{21}(f) = ae^{-2\pi j f \tau} \left[1 - \frac{(Q_r/Q_c \cos \phi)e^{j\phi}}{2jQ_r x} \right], \quad (\text{A1})$$

where $x \equiv (f - f_r)/f_r$, the quality factors are as in the main text, a is a complex feedline attenuation, and τ is the feedline delay. This model takes into account any impedance mismatch that gives rise to an asymmetric transmission line shape by allowing Q_c to be complex, with a phase ϕ which represents an angle of rotation between the resonance circle in the complex plane and the off-resonance baseline transmission.

The temperature of the mixing chamber was ramped from the 10 mK base temperature to 350 mK in steps of 10 mK. At each temperature, the complex transmission $S_{21}(f)$ of the Al resonance is measured using a Copper Mountain M5090 vector network analyzer for RF stimulus powers ranging from $P_{\text{DAC}} = -5$ dBm to -75 dBm. The remainder of the RF readout chain is identical to that described in the main text. The acquired frequency spectra are fit to Eq. (A1) and the optimal parameters recorded for each temperature, power pair. The resonance feature in $S_{21}(f)$ as a function of temperature is shown for an RF stimulus power of -30 dBm in Fig. 10. These data were collected in a temperature sweep of the refrigerator performed after the February calibration run.

The collected data are fit as a function of temperature to the following models for the dependence of resonator line shape on temperatures:

$$f_r(T) = f_r(0) \left(1 - \frac{1}{2} \alpha \kappa_2(T, f_r(0), \Delta) n_{\text{qp}}(T, \Delta) \right) \quad (\text{A2})$$

$$Q_i(T) = \left(\alpha \kappa_1(T, f_r(0), \Delta) n_{\text{qp}}(T, \Delta) + \frac{1}{Q_i(0)} \right)^{-1}, \quad (\text{A3})$$

with $\kappa_{1,2}$ as in [30], and the quiescent density of quasiparticles at temperature T taken to be

$$n_{\text{qp}} = 2N_0 \sqrt{2\pi k_B T \Delta} e^{-\Delta/k_B T}, \quad (\text{A4})$$

where N_0 is the single-spin density of states [31]. The fit results are summarized in Table III. The values of α and Δ used in the main text are adopted from [7]. We adopt canonical values: $f_t(0) = 4.24198$ GHz for all RF readout powers, and $Q_i(0) = 3.7 \times 10^5 (4.3 \times 10^7)$ for $P_{\text{DAC}} = -15 (-30)$ dBm, for the analyses in the main text, as measured for FNAL-I at NEXUS. This choice was made due to poor temperature instrumentation on the RF payload plate which led to an overestimation of device temperature for these data. This deficit was corrected in future runs of the NEXUS dilution refrigerator. No such issue was present in [7], and their measured values of α and Δ match more closely with literature [21, 25].

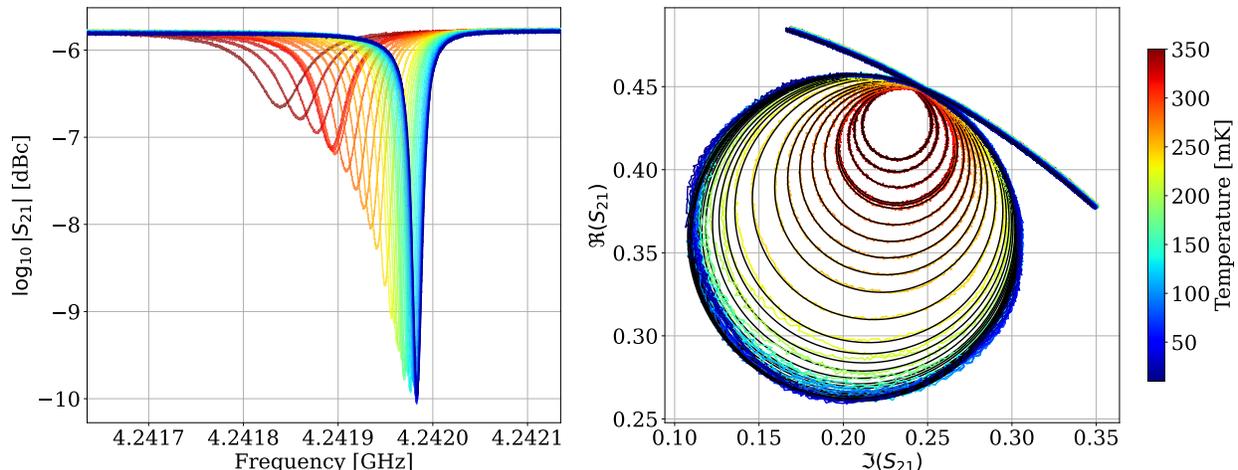


FIG. 10. The forward transmission $S_{21}(f)$ of the phonon-absorbing resonator on FNAL-I at $P_{\text{DAC}} = -30$ dBm, shown as $\log_{10}|S_{21}(f)|$ vs f (left) and in the complex plane (right) as a function of mixing chamber temperature. Black lines indicate fits of Eq. (A1) to the resonance circle.

Appendix B: Noise Characterization

The noise present in an on-resonance timestream directly impacts the baseline energy resolution of a KIPM detector. As such, understanding the noise sources present and their impact is important for optimizing detectors for energy resolution. The on-resonance timestream is acquired simultaneously with two calibration tones at $f_r \pm 10$ MHz for removal of correlated noise. This is repeated at RF stimulus powers ranging from $P_{\text{DAC}} = -15$ dBm to -75 dBm. The PSD $J(f)$ of the noise in the phase and magnitude readout quadratures are then generated for each RF power. Using the resonance line shape, these are converted to PSDs of fluctuations in fractional resonant frequency shift $\delta f_r/f_r$ and fluctuations on inverse quality factor $\delta(1/Q)$. They are further converted to fluctuations in quasiparticle density as measured by the frequency and dissipation shifts, as shown in Fig. 11. The pulse data for the energy resolution measurement in this work is taken at the highest power shown.

The observed noise spectra are white at the lowest readout power, where amplifier noise dominates. As readout power increases ($P_g = -112.5$ dBm to $P_g = -96.5$ dBm on the device feedline), the presence of noise from electrically active two-level systems (TLS) appears in the frequency quadrature. The noise power from TLS, $J_{\text{TLS}}(f)$, at a given frequency f_0 should scale as a power

law:

$$J^{\text{TLS}}(f = f_0|P_g) \propto P_g^{-1/2}, \quad (\text{B1})$$

for frequency quadrature readout [29]. The best power-law fit to the noise power at 500 Hz for a range of RF stimulus powers where TLS is dominant is shown in Fig. 12, returning an exponent of -0.61 ± 0.04 . The power-law fit to the dissipation quadrature data returns an exponent of -1.02 ± 0.03 , consistent with the scaling of white amplifier noise with readout power. The uncertainties are statistical only, and are returned by the fitting routine. The absence of this noise in the dissipation direction, as well as the dependence on noise power as a function of readout power indicate this is TLS noise. At the highest readout powers, extraneous noise arises in both the κ_1 and κ_2 readout quadratures. The source of this noise is currently unknown.

As shown in [7], the κ_2 timestream can be cleaned of correlated noise with the κ_1 timestream where TLS noise is not present, using the same formalism for cleaning on-resonance tones with the off-resonant calibration tones. For our data, this noise reduction is insignificant, indicating the noise in κ_1 and κ_2 is largely uncorrelated. The cleaned κ_2 PSD can then be fit to a noise model containing contributions from white amplifier noise and TLS noise, given by

$$J(f) = J_{\text{TLS}}(f) + A_w J_w(f) = A_{\text{TLS}} f^n \left| \frac{1}{1 + 2jQ_r(f/f_r)} \right|^2 + A_w J_w(f), \quad (\text{B2})$$

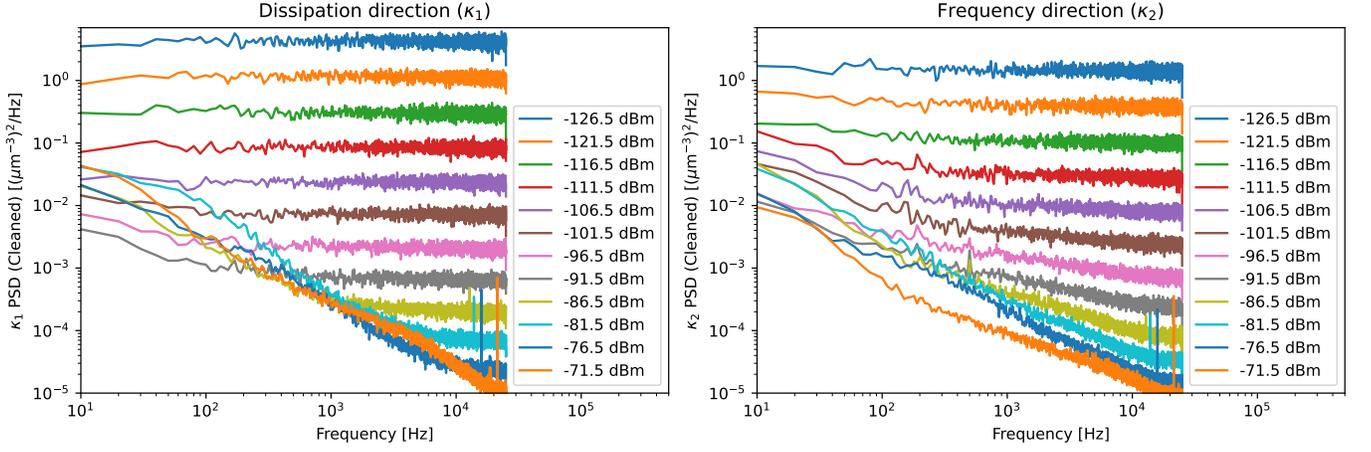


FIG. 11. The noise PSDs, in units of quasiparticle density fluctuations, after correlated noise removal as measured by the frequency and dissipation readout quadratures. The color indicates the RF power on the feedline of the device for each noise acquisition.

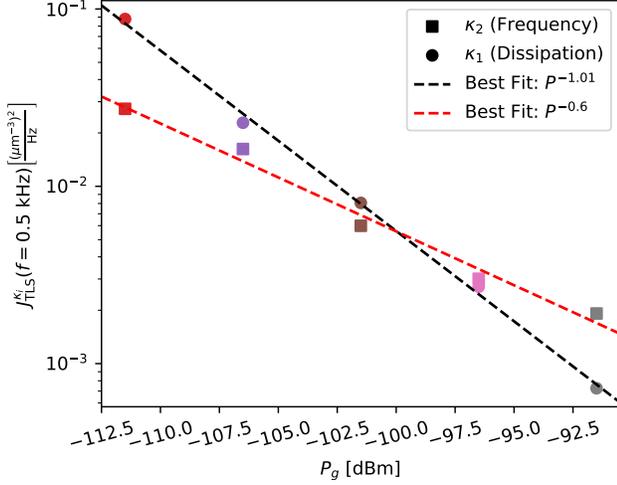


FIG. 12. Dependence of the magnitude of TLS noise at $f_0 = 500$ Hz as a function of readout power present on the device feedline. The circles(squares) are quasiparticle fluctuation power as measured by $\kappa_1(\kappa_2)$. The black and red dashed lines indicate the best fit of these data to a power law.

where A_{TLS} is the magnitude of the noise power from TLS, n is the TLS frequency-dependence exponent, f_r is the resonant frequency, and Q_r is the total quality factor. The white noise component $J_w(f)$ in the model is taken to be the κ_2 PSD for the lowest readout power and its contribution to the overall noise power A_w is allowed to float in the fit. The TLS contribution is modified by the resonator's response function (equivalently, a low-pass filter) which rolls off at a frequency $f_r/(2Q_r)$ [29]. In this term, the resonator quality factor Q_r is another free parameter in the fit (though the result is only 15% off from the measured value). This cleaning and fit to the noise model is shown in Fig. 13. We find a frequency

dependence for the TLS contribution of $n = -0.823 \pm 0.007$, whereas $n = -0.5$ is typically expected for TLS noise [29]. It is clear that our noise is TLS-dominated, even at readout powers where the unknown $\kappa_1 - \kappa_2$ noise arises.

Appendix C: Resolution Model

For a set of LED flashes with the same settings, the substrate will absorb an average number of photons \bar{N}_γ in each flash, corresponding to an average energy deposition of $\bar{E}_{\text{dep}} = \bar{N}_\gamma h\nu$, where $h\nu$ is the energy of an individual

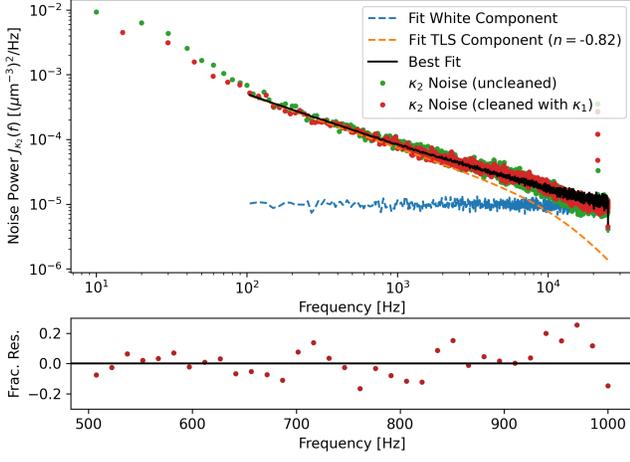


FIG. 13. The κ_2 Noise PSD for $P_g = -71.5$ dBm, as used in the LED calibration, is shown before cleaning with κ_2 (green points) and after cleaning (red points). These data are fit (black line) to a model comprising a TLS-noise term (orange dashed line) and a white-noise term (blue dashed line), for $f > 100$ Hz. Below this, a steeper frequency dependence in the noise power is observed. The lower panel shows the fractional residual of the cleaned data to our model in the 0.5 – 1 kHz region.

photon. Due to the Poisson statistics of this process, the variance in the number of photons deposited in the substrate is $\sigma_{N_\gamma}^2 = \bar{N}_\gamma$, giving a fluctuation in number of photons deposited of

$$\sigma_{N_\gamma} = \sqrt{\bar{N}_\gamma}, \quad (\text{C1})$$

which corresponds to fluctuations in deposited energy of

$$\sigma_E^{\text{dep}} = h\nu\sqrt{\bar{N}_\gamma}. \quad (\text{C2})$$

Only a fraction $\eta_{\text{ph}} < 1$ of the energy deposited is absorbed by the superconductor: $\bar{E}_{\text{abs}} = \eta_{\text{ph}}\bar{E}_{\text{dep}}$. The resolution in deposited energy is scaled by the phonon collection efficiency η_{ph} to find the resolution on energy absorbed by the superconductor:

$$\sigma_E^{\text{abs}} = (h\nu)\eta_{\text{ph}}\sqrt{\bar{N}_\gamma}. \quad (\text{C3})$$

A further scaling factor is applied to determine the fluctuations in device readout units due to the photon shot noise. Assuming linearity in device response to absorbed energy, we can define R to be the responsivity per unit energy absorbed by the superconductor, and thus the mean device response to photon bursts carrying a mean number of photons \bar{N}_γ is

$$\mu = R\bar{E}_{\text{abs}} = R\eta_{\text{ph}}\bar{E}_{\text{dep}} \quad (\text{C4})$$

$$= R\eta_{\text{ph}}\bar{N}_\gamma h\nu. \quad (\text{C5})$$

Similarly, the fluctuation in device readout is

$$\sigma_{\text{LED}} = R\sigma_E^{\text{abs}} = (h\nu)\eta_{\text{ph}}R\sqrt{\bar{N}_\gamma}. \quad (\text{C6})$$

Inverting Eq. (C4) and inserting into Eq. (C6) for \bar{N}_γ yields

$$\sigma_{\text{LED}}^2 = \mu \cdot (h\nu)\eta_{\text{ph}}R. \quad (\text{C7})$$

The distribution of pulse amplitudes from a set of LED pulses has a two contributions to its width σ : a term from the intrinsic, zero-energy, noise of the device (σ_0) and the broadening due to photon shot noise:

$$\sigma = \sqrt{\sigma_0^2 + \sigma_{\text{LED}}^2} = \sqrt{\sigma_0^2 + \mu \cdot (h\nu)\eta_{\text{ph}}R} \quad (\text{C8})$$

$$= \sqrt{\sigma_0^2 + \mu \cdot r}, \quad (\text{C9})$$

where we have defined

$$r = (h\nu)\eta_{\text{ph}}R, \quad (\text{C10})$$

to be the device responsivity per photon deposited in the substrate (as $\mu = r\bar{N}_\gamma$).

If we then take the resonator equation for fractional frequency shift due to a change in quasiparticle density δn_{qp} , and differentiate it with respect to energy, we find²

$$R = \left| \frac{d(\delta f/f)}{dE_{\text{abs}}} \right| = \frac{\alpha}{2} \kappa_2 \frac{d(\delta n_{\text{qp}})}{dE_{\text{abs}}} = \frac{\alpha}{2} \kappa_2 \frac{1}{V\Delta}, \quad (\text{C11})$$

where α is the kinetic inductance fraction, V is the volume of the phonon absorber, and κ_2 is a function of readout frequency, device temperature, and the Cooper pair binding energy Δ , as described in the main text. The responsivity of the device per unit energy deposited in the substrate is then

$$r = \alpha \frac{\kappa_2}{V} \frac{h\nu}{2\Delta} \eta_{\text{ph}}. \quad (\text{C12})$$

Appendix D: Uncertainty in Resolution of Quasiparticle Density

The fractional shift in resonant frequency and quality factor induced by an increase in quasiparticle density by an amount δn_{qp} are given [30] by

$$\frac{\delta f_r}{f_r} = -\frac{1}{2} \alpha \kappa_2(T, \omega, \Delta) \delta n_{\text{qp}} \quad (\text{D1})$$

$$\delta \frac{1}{Q_i} = -\alpha \kappa_1(T, \omega, \Delta) \delta n_{\text{qp}}, \quad (\text{D2})$$

where α is the kinetic inductance fraction, and $\kappa_{1(2)}(T, \omega, \Delta)$ carries units of volume and is the

² From [30] Eq. 2.59, we see $\delta f/f = -\frac{\alpha}{2} \kappa_2 n_{\text{qp}}$. We are interested in determining how this changes with respect to energy absorbed by the superconductor. Since α, κ_2 are independent of deposited energy, we must find $d/dE_{\text{abs}}(n_{\text{qp}})$. The density of quasiparticles increases by $2/V$ for every 2Δ deposited, thus $d/dE_{\text{abs}}(n_{\text{qp}}) = \frac{1}{V\Delta}$.

real(imaginary) component of the fractional change in complex conductivity per unit change in quasiparticle density as a function of temperature, readout frequency (ω), and superconducting gap energy at zero temperature (Δ), expressions for which are given in [30]. As such, inferring δn_{qp} (and subsequently the resolution on this value) from shifts in resonator characteristics requires calculation of κ_1 or κ_2 :

$$\sigma_{\text{qp}}^{\kappa_2} = \frac{2}{\alpha\kappa_2(T)}\sigma^{\delta f_r/f_r} \quad (\text{D3})$$

$$\sigma_{\text{qp}}^{\kappa_1} = \frac{1}{\alpha\kappa_1(T)}\sigma^{1/Q_i}, \quad (\text{D4})$$

for a fixed Δ and readout frequency.

The question is, at what temperature does one evaluate $\kappa_{1,2}$? Given that this resolution is on excess quasiparticle density over the quiescent, thermal density of quasiparticles $n_{\text{qp},0}$, one should insert the temperature of the Cooper pairs in the superconductor. It is obvious that

the Cooper pair temperature cannot be lower than that of its environment, but what is the upper bound? The quasiparticle lifetime τ_{qp} is set by $n_{\text{qp},0}$, as their product is a constant [41]. Thus, by measuring τ_{qp} , one knows $n_{\text{qp},0}$, from which an effective Cooper pair temperature can be determined using theoretical predictions [36]:

$$n_{\text{qp}}(T) = 2N_0\sqrt{2\pi k_B T}e^{-\Delta/k_B T}. \quad (\text{D5})$$

As discussed in section VI, at the lowest temperatures, τ_{qp} plateaued at 6.5 ms, the corresponding thermal quasiparticle density is $n_{\text{qp},0} = 18.5 \mu\text{m}^{-3}$, from which we extract an effective temperature of the Cooper pairs of $T_{\text{eff}} = 172$ mK. The value of κ_2 over the temperature range between the environment temperature (10 mK) up to T_{eff} changes by 9.1%. This is the fractional uncertainty we adopt in the text when converting between resolution on changes in resonator properties and resolution on quasiparticle density fluctuations.

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TABLE III. Results of the resonator characteristic fits to Mattis-Bardeen theory for $P_{\text{DAC}} = -15$ and -30 dBm from this work compared to the measurement in [7] of an identical device at -30 dBm.

	This work (-15 dBm)	This work (-30 dBm)	[7] (-30 dBm)
$f_r(0)$ [GHz]	$4.241968 \pm (7 \times 10^{-6})$	$4.241974 \pm (8 \times 10^{-6})$	4.2420
$Q_i(0)$	$(3.7 \pm 0.3) \times 10^5$	$(4.2 \pm 0.3) \times 10^5$	4.1×10^5
α [%]	0.2 ± 0.3	0.2 ± 0.2	3.80
Δ [meV]	0.14 ± 0.03	0.13 ± 0.03	0.184